# INDIAN INSTITUTE OF TECHNOLOGY BOMBAY



#### MATERIALS MANAGEMENT DIVISION

Powai, Mumbai 400076

### Reference No. 10000015464 (For RFx No. 6100000640)

Technical Specifications of Spare parts of RF Plasma Source for Nitrogen of MBE System

Application: Growth of high-quality GaN and related III-Nitride material for electronic and optoelectronic application.

RF Plasma Source for Nitrogen should perform precise and controllable growths resulting in high-quality electronic and optoelectronic devices.

#### Plasma Bulb:

- The plasma source should be of brazed bulb design. Brazing the bulb to the plasma source leads to the best seal; drastically lowering the possibility of leakage and greatly improving the plasma control.
- A plasma chamber should be constructed of all PBN (Pyrolitic Boron Nitride) to lower the risk of oxidation inside the bulb.
- The plasma chamber should be constructed with a single piece PBN gas inlet tube and plasma bulb to eliminate gas leakage around the bulb.

#### **Nozzle**

- **Nozzle should be designed Using competent (e.g. Monte Carlo) Software.** The software must tale many variables into account, like source to substrate distance, gas flow, system geometry, etc. so as to produce the best uniformity and end devise quality.
- Plasma source should provide field Replaceable Nozzle facility. This is a essential to change flux profile with another customized nozzle.
- The exit hole design should be such that it minimizes ion content in the beam while the active and neutral species (atomic and molecular) are directed toward the substrate.
- Nozzles should be applicable for most commercial MBE systems and ensure typical uniformity of  $\pm 1\%$ .

#### Water Cooled RF Feedthrough

RF Plasma source should have water cooled **RF Feedthrough.** The water cooled RF Feedthrough on the Nitrogen Plasma Source effectively takes heat away from sensitive in-vacuum to out-vacuum transition areas.

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### **Demonstrated Performance**

The manufacturer must have proven its competence by already demonstrating state of the art results. Legitimate proofs must be provided so as to establish the following results.

- Demonstrated growth of AlGaN/GaN two-dimensional electron gas structures with record high mobility greater than 150,000 cm<sup>2</sup>/V.sec below 20K and >50,000 cm<sup>2</sup>/Vsec at 77K
- Demonstrated production of AlGaN/GaN PI-HEMTs which show small signal RF performance and DC breakdowns as a function of gate length that are as good as the best transistors made by MOVPE
- GaN growth rates as high as 2.5µm/hr.
- The metastable molecules to exhibit a high incorporation rate in GaN growth and stabilize the growth rate at high substrate temperatures (approx. 700-750°C.)

## Specification for RF Power supply/RF Generator and AUTOTUNER

- 1. RF Power Supply/RF Generator: 600 W RF Generator (13.56MHz), with 7m cable.
- **2. Autotuner should** Consists of a controller, matching unit, and required cables to connect the Nitrogen plasma source compatible power supply
- **3.** The auto tuner should automatically control RF Power Supply/RF Generator with auto tuner set adjust and maintains the plasma source conditions without the need for manual adjustments during experiments.
- **4.** Autotuner should be included to ensure stable growth conditions and to optimize power efficiencies.
- 5. Scope of Supply:
  - DC power supply module and power supply controller and should be configured for RF Plasma Source for generating Nitrogen plasma
  - DC Power Module
  - **RF** Plasma Source RF Generator
  - RF Power Connector Option
- **6.** RF Autotuner RF auto matching unit configured for Nitrogen Plasma Source.
- 7. RF Power Supply/RF Generator with auto tuner set should be compatible with RF source for Nitrogen.
- **8.** Supplier should show demonstration and working RF Power Supply/RF Generator with auto tuner set with the RF Plasma source for Nitrogen.



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**9.** Warranty: One year or longer.

10. Power Supply: Single Phase 220V, 50Hz. Indian power supply compatible.

## General Information:

1. India power supply: 220V Single phase 50Hz.

2. Warranty: One year or longer.